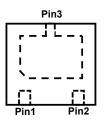


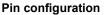
PTVSHC3N20VU

Uni-directional 20V High Capacitance TVS

Description

The PTVSHC3N20VU Transient Voltage Suppressor is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and PDA's. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, lower operating voltage, lower clamping voltage and no device degradation when compared to MLVs. The PTVSHC3N20VU protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. The PTVSHC3N20VU is available in a DFN2×2-3L package with working voltages of 20 volt.





Feature

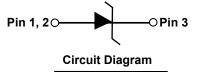
- 5600W Peak pulse power per line (t_P = 8/20µs)
- DFN2×2-3L package
- Response time is typically < 1 ns</p>
- Protect one I/O or power line
- Low clamping Voltage
- RoHS compliant
- Transient protection for data lines to IEC 61000-4-2(ESD)
 ±30KV(air), ±30KV(contact); IEC 61000-4-4 (EFT) 40A (5/50ns)

Applications

- Cell phone handsets and accessories
- Personal digital assistants (PDA's)
- Notebooks, desktops, and servers
- Portable instrumentation
- Cordless phones
- Digital cameras
- Peripherals
- MP3 players

Mechanical Characteristics

- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- Qualified max reflow temperature:260°C

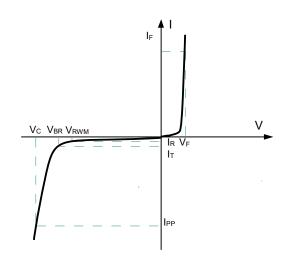




PTVSHC3N20VU

Electronics Parameter

Symbol	Parameter	
VRWM	Peak Reverse Working Voltage	
IR	Reverse Leakage Current @ VRWM	
V _{BR}	Breakdown Voltage @ I⊤	
Ι _Τ	Test Current	
IPP	Maximum Reverse Peak Pulse Current	
Vc	Clamping Voltage @ IPP	
P _{PP}	Peak Pulse Power	
CJ	Junction Capacitance	
lF	Forward Current	
VF	Forward Voltage @ I⊧	



Electrical characteristics per line@25°C(unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	VRWM				20	V
Breakdown Voltage	V _{BR}	I _t =1mA	21	23	25	V
Reverse Leakage Current	IR	V _{RWM} =20V			1	μA
Clamping Voltage	Vc	I _{PP} =60A t _P = 8/20μs		28	30	V
Clamping Voltage	Vc	I _{PP} =136A t _P = 8/20µs		34	36	V
Clamping Voltage	Vc	I _{PP} =160A t _P = 8/20µs		36	38	V
Junction Capacitance	Cj	V _R =0V f = 1MHz		900	1100	pF

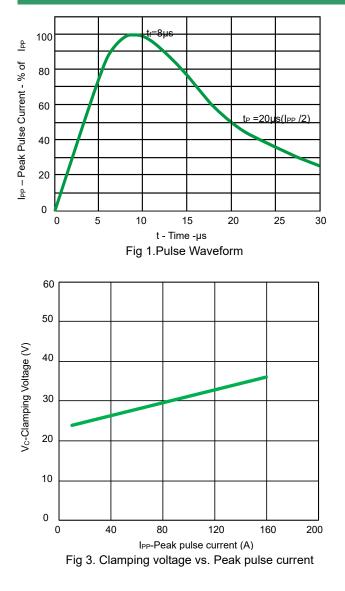
Notes : Measured from pin 3 to pin 1 and pin 2.

Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Peak Pulse Power ($t_P = 8/20\mu S$)	P _{pp}	5600	W
Peak Pulse Current (tp=8/20µs)	I _{pp}	160	A
Lead Soldering Temperature	TL	260 (10 sec)	°C
Operating Temperature	TJ	-55 to 150	°C
Storage Temperature	T _{STG}	-55 to 150	°C

PTVSHC3N20VU

Typical Characteristics



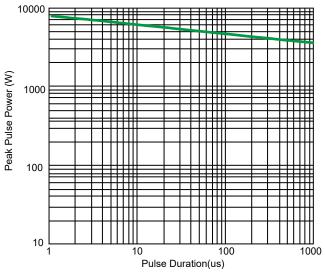


Fig 5. Non Repetitive Peak Pulse Power vs. Pulse time

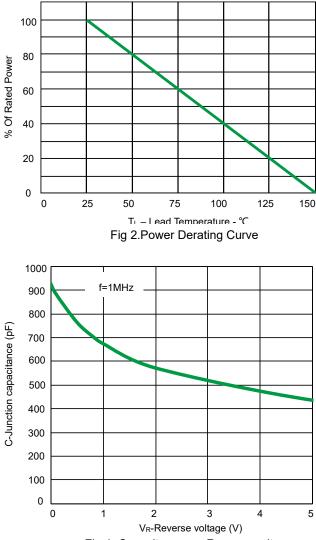


Fig 4. Capacitance vs. Reveres voltage

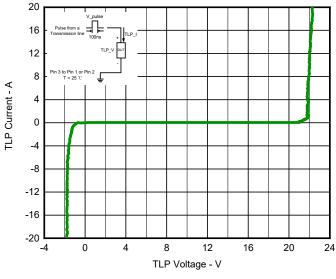
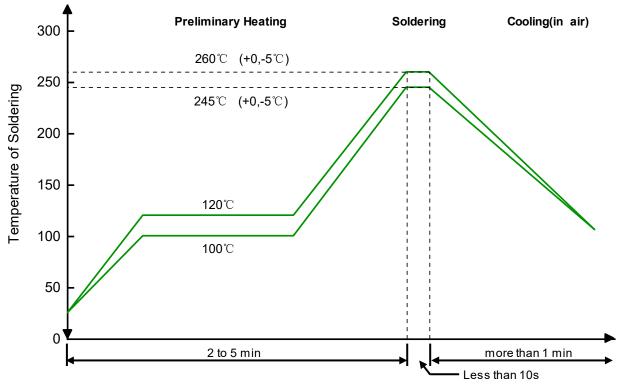


Fig 6. TLP Measurement

PTVSHC3N20VU

Solder Reflow Recommendation



Remark: Pb free for 260°C; Pb for 245°C.

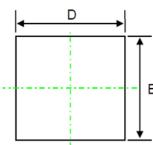
PCB Design

For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

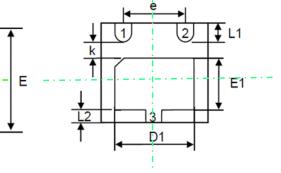
- > Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- Do not make false economies and save copper for the ground connection.
- Place via holes to ground as close as possible to the anode of the TVS diode.
- Use as many via holes as possible for the ground connection.
- Keep the length of via holes in mind! The longer the more inductance they will have.

PTVSHC3N20VU

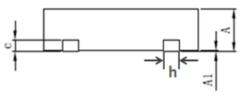
Product dimension (DFN2×2-3L)



Top View

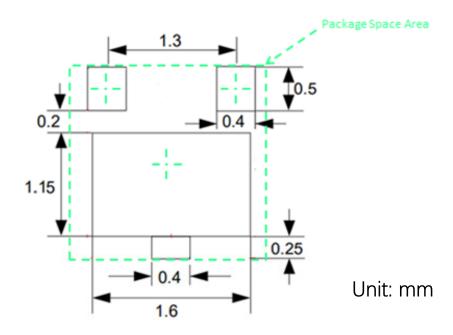


Bottom View



Side View

Dim	Millimeters			
Diili	MIN	Тур.	МАХ	
А	0.50	0.58	0.66	
D	1.90	2.00	2.10	
D1	1.40	1.50	1.60	
E	1.90	2.00	2.10	
E1	0.95	1.05	1.15	
е	1.30BSC			
L1	0.35	0.40	0.45	
k	0.20	0.30	0.40	
L2	0.20	0.25	0.30	
h	0.25	0.30	0.35	
с	0.15BSC			
A1	0.00	0.02	0.05	

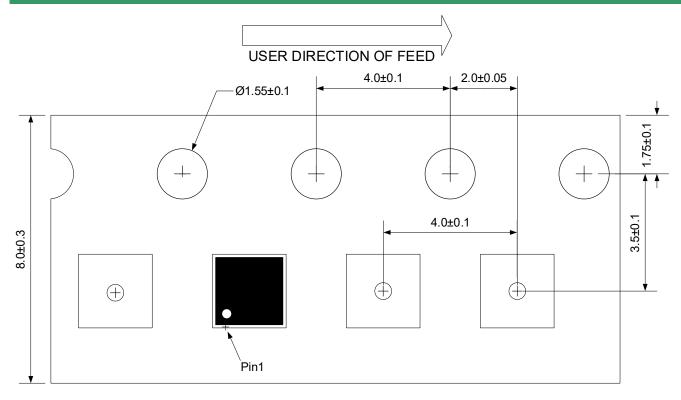


Ordering information

Device	Package	Reel	Shipping
PTVSHC3N20VU	DFN2×2-3L (Pb-Free)	7"	3000 / Tape & Reel

PTVSHC3N20VU

Load with information



Unit:mm

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